

BCR40RM-12LB

Triac
Medium Power Use

R07DS0516EJ0100

Rev.1.00

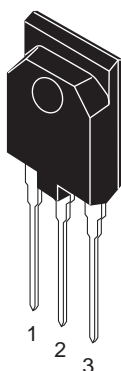
Oct 14, 2011

Features

- $I_{T(RMS)}$: 40A
- V_{DRM} : 600 V
- T_j : 150 °C
- I_{FGT} , I_{RGT} , I_{RGT} :50 mA
- Viso:2000V
- Insulated Type
- Planar Passivation Type

Outline

RENESAS Package code: PRSS0003ZA-A
(Package name: TO-3PFM)



1. T_1 Terminal
2. T_2 Terminal
3. Gate Terminal

Applications

Contactless AC switch, electric heater control, light dimmer, on/off and speed control of small induction motor, on/off control of copier lamp

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		12	
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	600	V
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	720	V

Notes: 1. Gate open.

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I_T (RMS)	40	A	Commercial frequency, sine full wave 360° conduction, $T_c = 61^\circ\text{C}$ ^{Note3}
Surge on-state current	I_{TSM}	400	A	60Hz sinewave 1 full cycle, peak value, non-repetitive
I^2t for fusion	I^2t	667	A^2s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P_{GM}	5	W	
Average gate power dissipation	$P_{G(AV)}$	0.5	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I_{GM}	2	A	
Junction Temperature	T_j	-40 +150	$^\circ\text{C}$	
Storage temperature	T_{stg}	-40 +150	$^\circ\text{C}$	
Mass	—	5.2	g	Typical value
Isolation voltage	Viso	2000	V	$T_a=25^\circ\text{C}$, AC 1 minute T_1 T_2 G terminal to case

Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Repetitive peak off-state current	I_{DRM}	—	—	10.0	mA	$T_j = 150^\circ\text{C}$, V_{DRM} applied
On-state voltage	V_{TM}	—	—	1.55	V	$T_c = 25^\circ\text{C}$, $I_{TM} = 60\text{A}$, instantaneous measurement
Gate trigger voltage ^{Note2}	I V_{FGTI}	—	—	2.5	V	$T_j = 25^\circ\text{C}$, $V_D = 6\text{V}$, $R_L = 6\ \Omega$, $R_G = 330\ \Omega$
	II V_{RGTI}	—	—	2.5	V	
	III V_{RGTIII}	—	—	2.5	V	
Gate trigger current ^{Note2}	I I_{FGTI}	—	—	50	mA	$T_j = 25^\circ\text{C}$, $V_D = 6\text{V}$, $R_L = 6\ \Omega$, $R_G = 330\ \Omega$
	II I_{RGTI}	—	—	50	mA	
	III I_{RGTIII}	—	—	50	mA	
Gate non-trigger voltage	V_{GD}	0.2	—	—	V	$T_j = 125^\circ\text{C}$, $V_D = 1/2 V_{DRM}$
		0.1	—	—	V	$T_j = 150^\circ\text{C}$, $V_D = 1/2 V_{DRM}$
Thermal resistance	$R_{th(j-c)}$	—	—	1.8	$^\circ\text{C/W}$	Junction to case ^{Note3}
Critical-rate of rise of off-state commutation voltage ^{Note4}	$(dv/dt)_c$	20	—	—	V/ μs	$T_j = 125^\circ\text{C}$
		2	—	—	V/ μs	$T_j = 150^\circ\text{C}$

Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

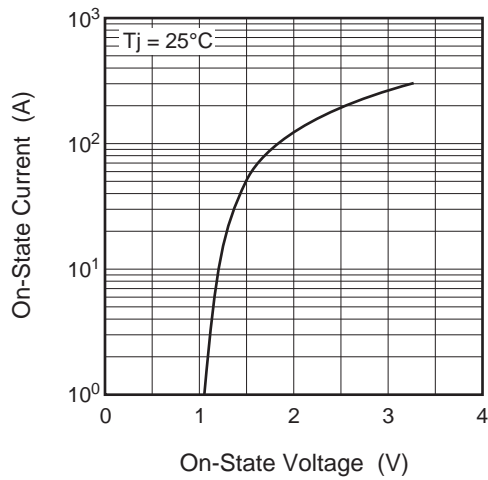
3. The contact thermal resistance $R_{th(c-f)}$ in case of greasing is 0.5°C/W .

4. Test conditions of the critical-rate of rise of off-state commutating voltage shown in the table below.

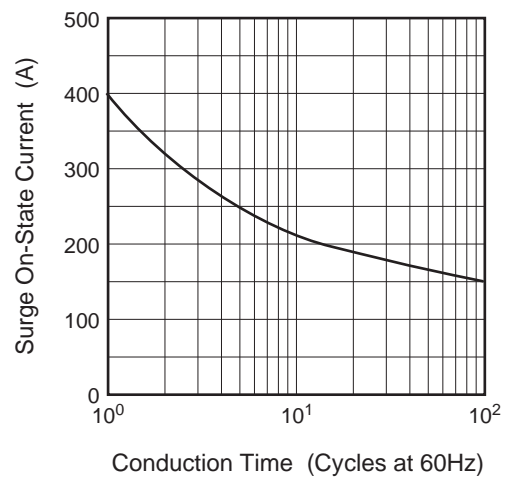
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature $T_j = 125/150^\circ\text{C}$ 2. Rate of decay of on-state commutating current $(di/dt)_c = -20\text{ A/ms}$ 3. Peak off-state voltage $V_D = 400\text{ V}$	

Performance Curves

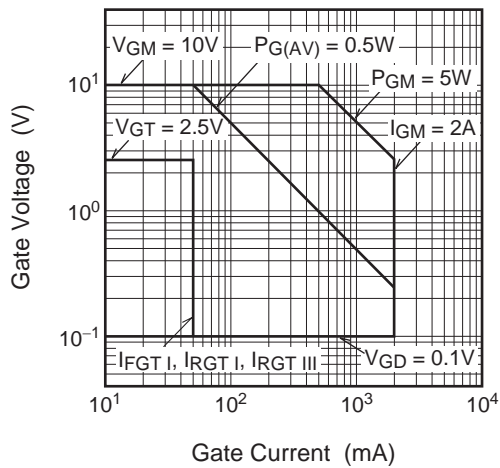
Maximum On-State Characteristics



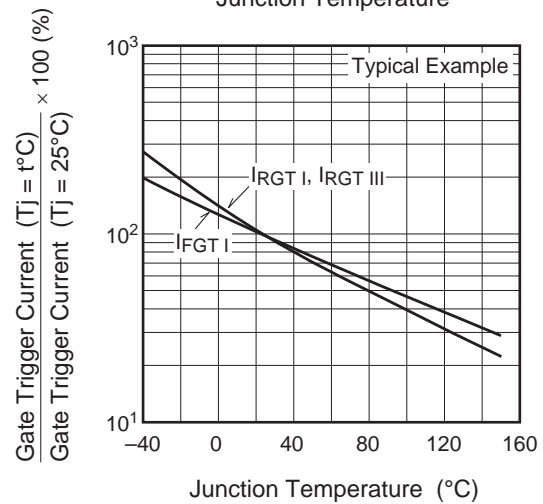
Rated Surge On-State Current



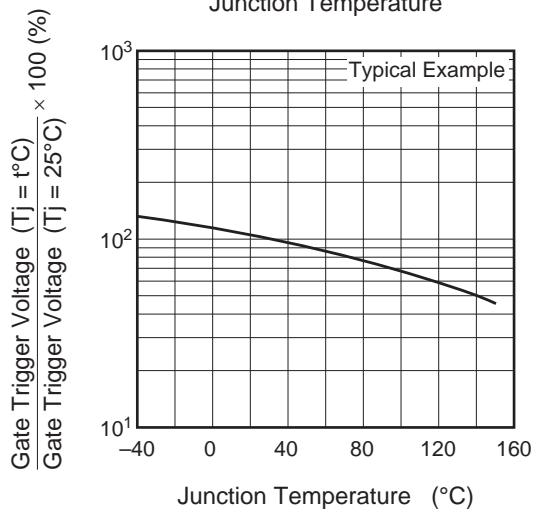
Gate Characteristics (I, II and III)



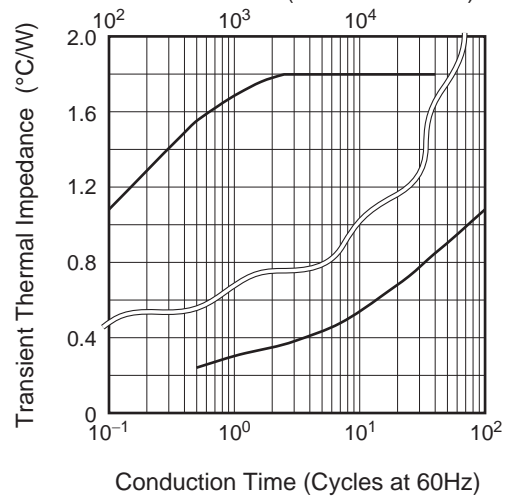
Gate Trigger Current vs. Junction Temperature



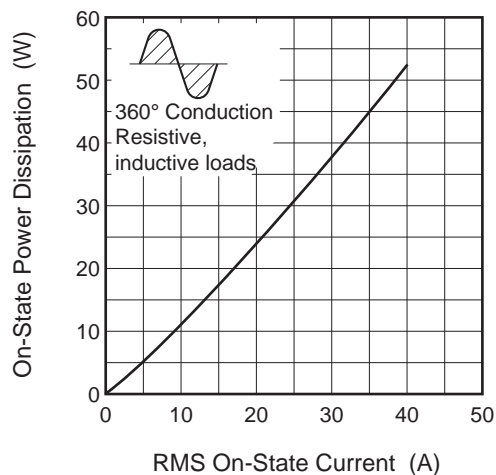
Gate Trigger Voltage vs. Junction Temperature



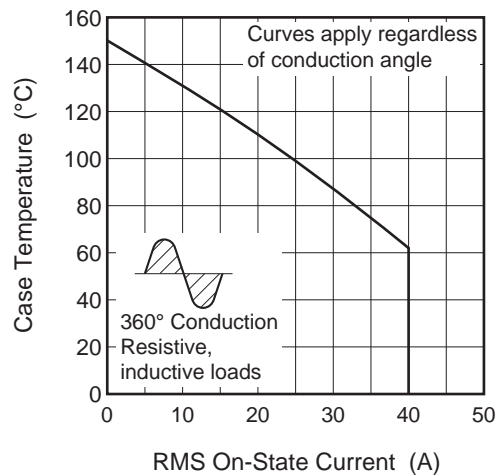
Maximum Transient Thermal Impedance Characteristics (Junction to case)



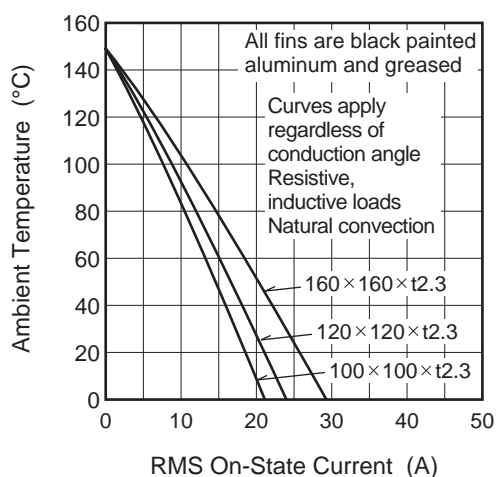
Maximum On-State Power Dissipation



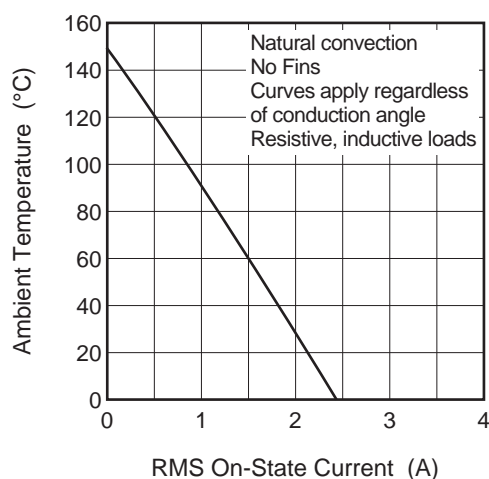
Allowable Case Temperature vs. RMS On-State Current



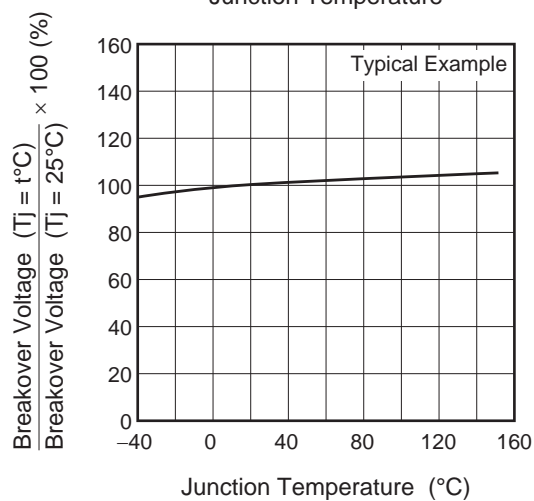
Allowable Ambient Temperature vs. RMS On-State Current



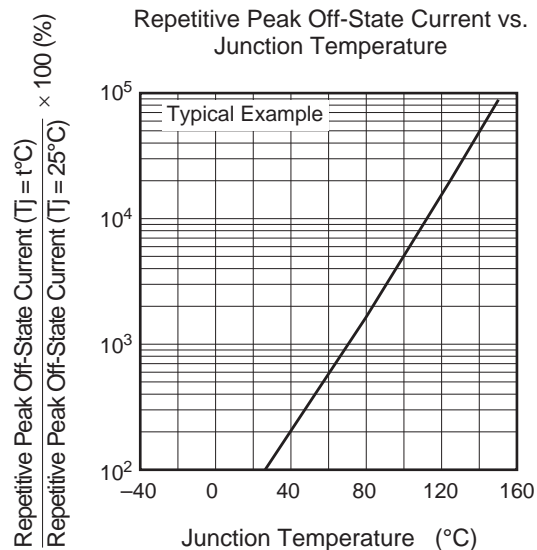
Allowable Ambient Temperature vs. RMS On-State Current

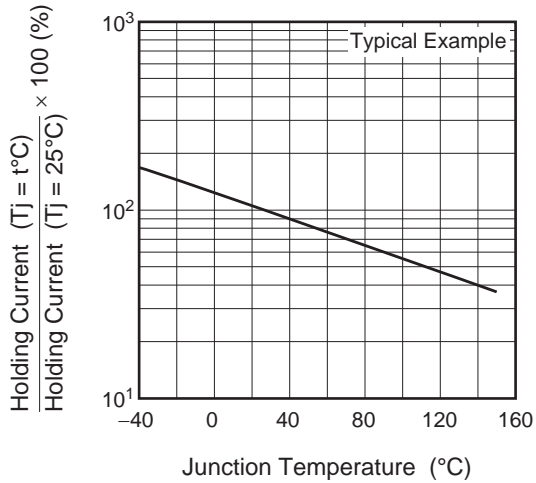
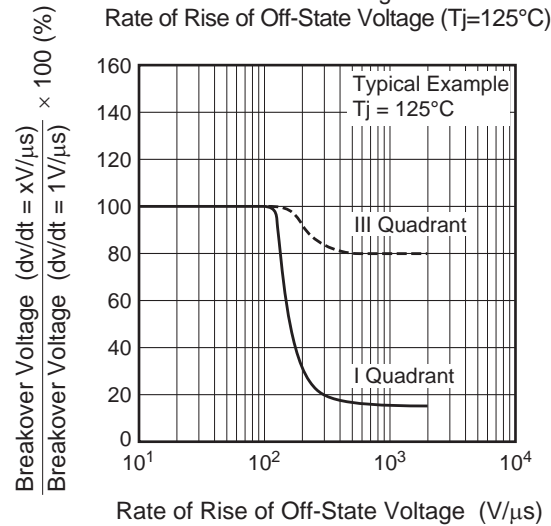
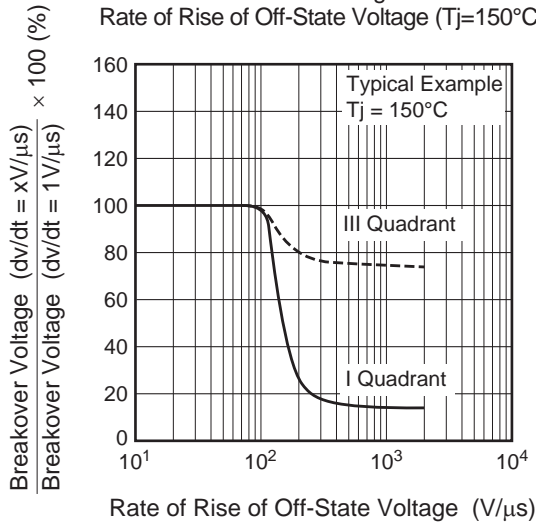
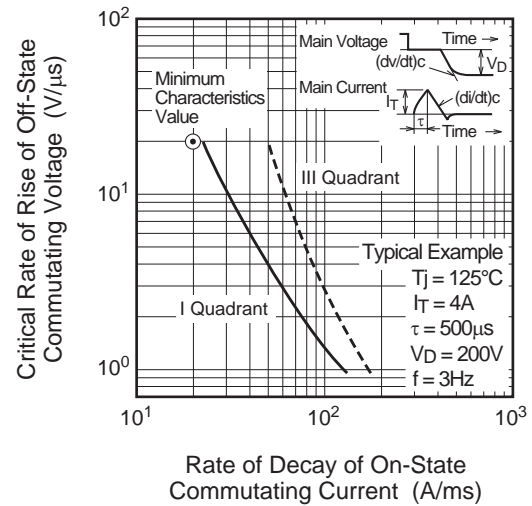
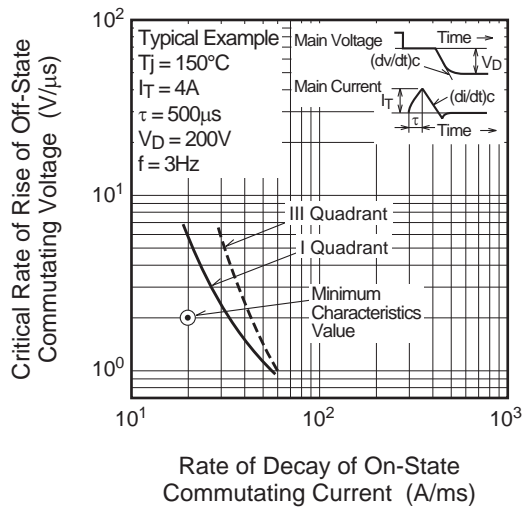
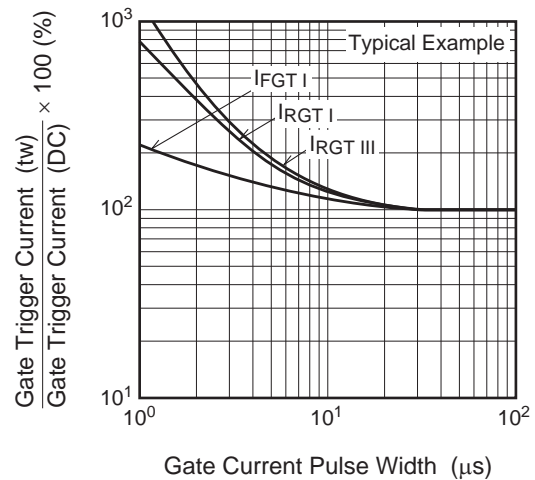


Breakover Voltage vs. Junction Temperature

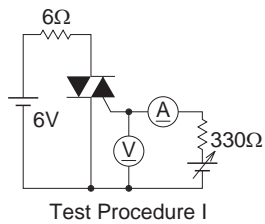


Repetitive Peak Off-State Current vs. Junction Temperature

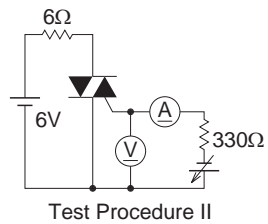


Holding Current vs.
Junction TemperatureBreakover Voltage vs.
Rate of Rise of Off-State Voltage ($T_j=125^\circ\text{C}$)Breakover Voltage vs.
Rate of Rise of Off-State Voltage ($T_j=150^\circ\text{C}$)Commutation Characteristics ($T_j=125^\circ\text{C}$)Commutation Characteristics ($T_j=150^\circ\text{C}$)Gate Trigger Current vs.
Gate Current Pulse Width

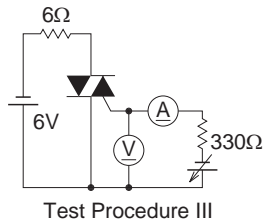
Gate Trigger Characteristics Test Circuits



Test Procedure I

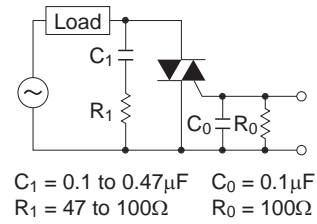


Test Procedure II



Test Procedure III

Recommended Circuit Values Around The Triac



$C_1 = 0.1 \text{ to } 0.47 \mu\text{F}$ $C_0 = 0.1 \mu\text{F}$
 $R_1 = 47 \text{ to } 100 \Omega$ $R_0 = 100 \Omega$

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